

16-Bit, 250ksps, $\pm 10.24V$ True Bipolar, Pseudo-Differential Input ADC with 93.5dB SNR

FEATURES

- 250ksps Throughput Rate
- $\pm 1.5\text{LSB}$ INL (Max)
- Guaranteed 16-Bit No Missing Codes
- Pseudo-Differential Inputs
- True Bipolar Input Ranges $\pm 6.25V$, $\pm 10.24V$, $\pm 12.5V$
- 93.5dB SNR (Typ) at $f_{IN} = 2\text{kHz}$
- -111dB THD (Typ) at $f_{IN} = 2\text{kHz}$
- Guaranteed Operation to 125°C
- Single 5V Supply
- Low Drift ($20\text{ppm}/^\circ\text{C}$ Max) $2.048V$ Internal Reference
- Onboard Single-Shot Capable Reference Buffer
- No Pipeline Delay, No Cycle Latency
- 1.8V to 5V I/O Voltages
- SPI-Compatible Serial I/O with Daisy-Chain Mode
- Internal Conversion Clock
- Power Dissipation 28mW (Typ)
- 16-Lead MSOP Package

APPLICATIONS

- Programmable Logic Controllers
- Industrial Process Control
- High Speed Data Acquisition
- Portable or Compact Instrumentation
- ATE

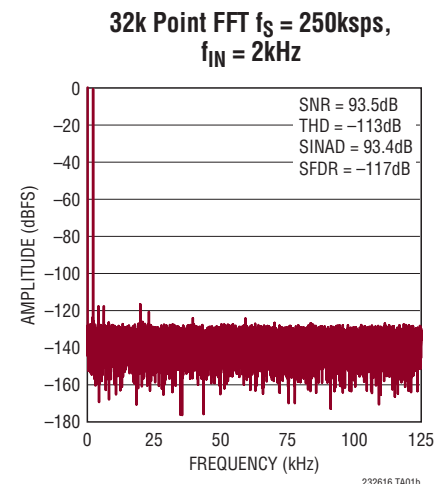
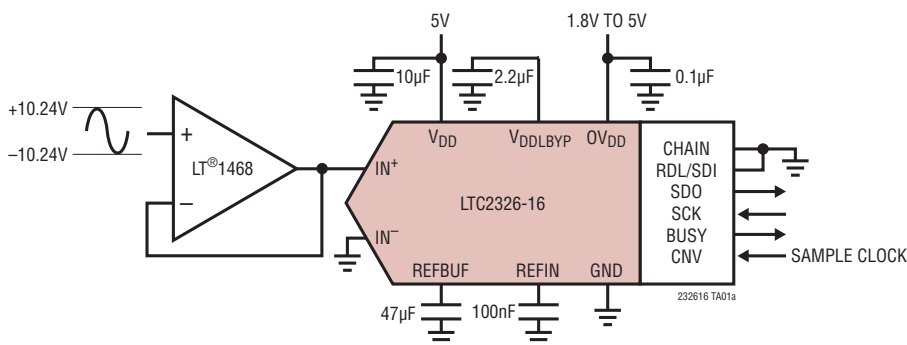
DESCRIPTION

The **LTC[®]2326-16** is a low noise, high speed 16-bit successive approximation register (SAR) ADC with pseudo-differential inputs. Operating from a single 5V supply, the LTC2326-16 has a $\pm 10.24V$ true bipolar input range, making it ideal for high voltage applications which require a wide dynamic range. The LTC2326-16 achieves $\pm 1.5\text{LSB}$ INL maximum, no missing codes at 16 bits with 93.5dB SNR.

The LTC2326-16 has an onboard single-shot capable reference buffer and low drift ($20\text{ppm}/^\circ\text{C}$ max) $2.048V$ temperature compensated reference. The LTC2326-16 also has a high speed SPI-compatible serial interface that supports 1.8V, 2.5V, 3.3V and 5V logic while also featuring a daisy-chain mode. The fast 250ksps throughput with no cycle latency makes the LTC2326-16 ideally suited for a wide variety of high speed applications. An internal oscillator sets the conversion time, easing external timing considerations. The LTC2326-16 dissipates only 28mW and automatically naps between conversions, leading to reduced power dissipation that scales with the sampling rate. A sleep mode is also provided to reduce the power consumption of the LTC2326-16 to $300\mu\text{W}$ for further power savings during inactive periods.

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TYPICAL APPLICATION



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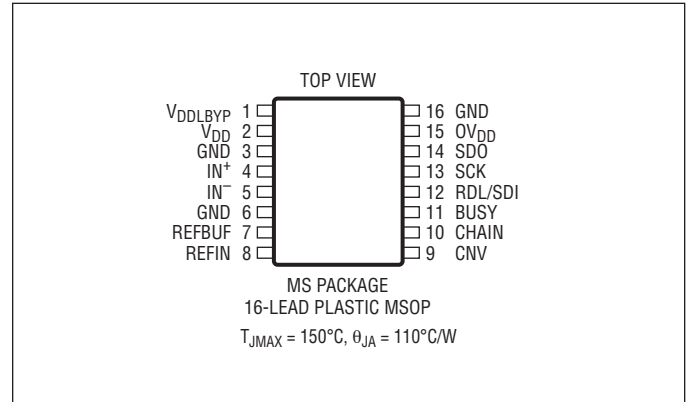
LTC2326-16

ABSOLUTE MAXIMUM RATINGS

(Notes 1, 2)

Supply Voltage (V_{DD})	6V
Supply Voltage (OV_{DD})	6V
Supply Bypass Voltage (V_{DDLBY})	3.2V
Analog Input Voltage	
IN^+ , IN^-	-16.5V to 16.5V
REFBUF	6V
REFIN	2.8V
Digital Input Voltage	
(Note 3)	(GND -0.3V) to (OV_{DD} + 0.3V)
Digital Output Voltage	
(Note 3)	(GND -0.3V) to (OV_{DD} + 0.3V)
Power Dissipation	500mW
Operating Temperature Range	
LTC2326C	0°C to 70°C
LTC2326I	-40°C to 85°C
LTC2326H	-40°C to 125°C
Storage Temperature Range	-65°C to 150°C

PIN CONFIGURATION



ORDER INFORMATION

<http://www.linear.com/product/LTC2326-16#orderinfo>

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC2326CMS-16#PBF	LTC2326CMS-16#TRPBF	232616	16-Lead Plastic MSOP	0°C to 70°C
LTC2326IMS-16#PBF	LTC2326IMS-16#TRPBF	232616	16-Lead Plastic MSOP	-40°C to 85°C
LTC2326HMS-16#PBF	LTC2326HMS-16#TRPBF	232616	16-Lead Plastic MSOP	-40°C to 125°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on nonstandard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreeel/>. Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{IN}^+	Absolute Input Range (IN ⁺)	(Note 5) ●	$-2.5 \cdot V_{REFBUF} - 0.5$		$2.5 \cdot V_{REFBUF} + 0.5$	V
V_{IN}^-	Absolute Input Range (IN ⁻)	(Note 5) ●	-0.5		0.5	V
$V_{IN}^+ - V_{IN}^-$	Input Differential Voltage Range	$V_{IN} = V_{IN}^+ - V_{IN}^-$ ●	$-2.5 \cdot V_{REFBUF}$		$2.5 \cdot V_{REFBUF}$	V
I_{IN}	Analog Input Current	●	-7.8		4.8	mA
C_{IN}	Analog Input Capacitance			5		pF
R_{IN}	Analog Input Resistance			2.083		k Ω
CMRR	Input Common Mode Rejection Ratio	$f_{IN} = 125\text{kHz}$		66		dB

CONVERTER CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
	Resolution	●	16			Bits
	No Missing Codes	●	16			Bits
	Transition Noise			0.5		LSB _{RMS}
INL	Integral Linearity Error	(Note 6) ●	-1.5	± 0.25	1.5	LSB
DNL	Differential Linearity Error	●	-1	± 0.1	1	LSB
BZE	Bipolar Zero-Scale Error	(Note 7) ●	-10	0	10	LSB
	Bipolar Zero-Scale Error Drift			0.01		LSB/ $^\circ\text{C}$
FSE	Bipolar Full-Scale Error	$V_{REFBUF} = 4.096\text{V}$ (REFBUF Overdriven) (Notes 7, 9) ●	-35		-35	LSB
		$REFIN = 2.048\text{V}$ (Note 7) ●	-45		45	LSB
	Bipolar Full-Scale Error Drift			± 0.5		ppm/ $^\circ\text{C}$

DYNAMIC ACCURACY

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$ and $A_{IN} = -1\text{dBFS}$. (Notes 4, 8)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
SINAD	Signal-to-(Noise + Distortion) Ratio	$\pm 6.25\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 1.25\text{V}$ ●	87.1	90.4		dB
		$\pm 10.24\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 2.048\text{V}$ ●	90.2	93.4		dB
		$\pm 12.5\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFBUF = 5\text{V}$ ●	90.5	94.2		dB
SNR	Signal-to-Noise Ratio	$\pm 6.25\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 1.25\text{V}$ ●	87.5	90.5		dB
		$\pm 10.24\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 2.048\text{V}$ ●	91	93.5		dB
		$\pm 12.5\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFBUF = 5\text{V}$ ●	92	94.5		dB
THD	Total Harmonic Distortion	$\pm 6.25\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 1.25\text{V}$ ●		-108	-98	dB
		$\pm 10.24\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 2.048\text{V}$ ●		-111	-98	dB
		$\pm 12.5\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFBUF = 5\text{V}$ ●		-106	-96	dB
SFDR	Spurious Free Dynamic Range	$\pm 6.25\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 1.25\text{V}$ ●	98	110		dB
		$\pm 10.24\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFIN = 2.048\text{V}$ ●	98	113		dB
		$\pm 12.5\text{V}$ Range, $f_{IN} = 2\text{kHz}$, $REFBUF = 5\text{V}$ ●	96	108		dB
	-3dB Input Linear Bandwidth			7		MHz
	Aperture Delay			500		ps
	Aperture Jitter			4		ps _{RMS}
	Transient Response	Full-Scale Step		1		μs

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INTERNAL REFERENCE CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{REFIN}	Internal Reference Output Voltage		2.043	2.048	2.053	V
	V_{REFIN} Temperature Coefficient	(Note 14)	●	2	20	ppm/ $^\circ\text{C}$
	REFIN Output Impedance			15		$\text{k}\Omega$
	V_{REFIN} Line Regulation	$V_{\text{DD}} = 4.75\text{V}$ to 5.25V		0.08		mV/V
	REFIN Input Voltage Range	(REFIN Overdriven) (Note 5)	1.25		2.4	V

REFERENCE BUFFER CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
V_{REFBUF}	Reference Buffer Output Voltage	$V_{\text{REFIN}} = 2.048\text{V}$	●	4.091	4.096	4.101	V
	REFBUF Input Voltage Range	(REFBUF Overdriven) (Notes 5, 9)	●	2.5	5	V	
	REFBUF Output Impedance	$V_{\text{REFIN}} = 0\text{V}$		13		$\text{k}\Omega$	
I_{REFBUF}	REFBUF Load Current	$V_{\text{REFBUF}} = 5\text{V}$ (REFBUF Overdriven) (Notes 9, 10) $V_{\text{REFBUF}} = 5\text{V}$, Nap Mode (REFBUF Overdriven) (Note 9)	●	0.56	0.6	mA	
				0.39		mA	

DIGITAL INPUTS AND DIGITAL OUTPUTS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{IH}	High Level Input Voltage		●	$0.8 \cdot OV_{\text{DD}}$		V
V_{IL}	Low Level Input Voltage		●		$0.2 \cdot OV_{\text{DD}}$	V
I_{IN}	Digital Input Current	$V_{\text{IN}} = 0\text{V}$ to OV_{DD}	●	-10	10	μA
C_{IN}	Digital Input Capacitance			5		pF
V_{OH}	High Level Output Voltage	$I_{\text{O}} = -500\mu\text{A}$	●	$OV_{\text{DD}} - 0.2$		V
V_{OL}	Low Level Output Voltage	$I_{\text{O}} = 500\mu\text{A}$	●		0.2	V
I_{OZ}	Hi-Z Output Leakage Current	$V_{\text{OUT}} = 0\text{V}$ to OV_{DD}	●	-10	10	μA
I_{SOURCE}	Output Source Current	$V_{\text{OUT}} = 0\text{V}$		-10		mA
I_{SINK}	Output Sink Current	$V_{\text{OUT}} = OV_{\text{DD}}$		10		mA

POWER REQUIREMENTS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
V_{DD}	Supply Voltage		●	4.75	5	5.25	V
OV_{DD}	Supply Voltage		●	1.71		5.25	V
I_{VDD}	Supply Current	250ksps Sample Rate ($IN^+ = -10.24\text{V}$, $IN^- = 0\text{V}$)	●		9.9	11.5	mA
		250ksps Sample Rate ($IN^+ = IN^- = 0\text{V}$)			5.6		mA
I_{OVDD}	Supply Current	250ksps Sample Rate ($C_L = 20\text{pF}$)			0.1		mA
I_{NAP}	Nap Mode Current	Conversion Done ($I_{VDD} + I_{OVDD}$, $IN^+ = -10.24\text{V}$, $IN^- = 0\text{V}$)	●		8.4	10	mA
I_{SLEEP}	Sleep Mode Current	Sleep Mode ($I_{VDD} + I_{OVDD}$)	●		60	225	μA
P_D	Power Dissipation	250ksps Sample Rate ($IN^+ = -10.24\text{V}$, $IN^- = 0\text{V}$)	●		50	57.5	mW
		250ksps Sample Rate ($IN^+ = IN^- = 0\text{V}$)			28		mW
	Nap Mode	Conversion Done ($I_{VDD} + I_{OVDD}$, $IN^+ = -10.24\text{V}$, $IN^- = 0\text{V}$)	●		42	50	mW
	Sleep Mode	Sleep Mode ($I_{VDD} + I_{OVDD}$)	●		0.3	1.1	mW

ADC TIMING CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
f_{SAMPL}	Maximum Sampling Frequency		●		250	ksps
t_{CONV}	Conversion Time		●	1.9	3	μs
t_{ACQ}	Acquisition Time	$t_{ACQ} = t_{CYC} - t_{HOLD}$ (Note 11)	●	3.460		μs
t_{HOLD}	Maximum Time between Acquisitions		●		540	ns
t_{CYC}	Time Between Conversions		●	4		μs
t_{CNVH}	CNV High Time		●	20		ns
$t_{BUSY\text{LH}}$	CNV \uparrow to BUSY Delay	$C_L = 20\text{pF}$	●		13	ns
t_{CNVL}	Minimum Low Time for CNV	(Note 12)	●	20		ns
t_{QUIET}	SCK Quiet Time from CNV \uparrow	(Note 11)	●	20		ns
t_{SCK}	SCK Period	(Notes 12, 13)	●	10		ns
t_{SCKH}	SCK High Time		●	4		ns
t_{SCKL}	SCK Low Time		●	4		ns
$t_{SSDISCK}$	SDI Setup Time From SCK \uparrow	(Note 12)	●	4		ns
$t_{HSDISCK}$	SDI Hold Time From SCK \uparrow	(Note 12)	●	1		ns
t_{SCKCH}	SCK Period in Chain Mode	$t_{SCKCH} = t_{SSDISCK} + t_{DSDO}$ (Note 12)	●	13.5		ns
t_{DSDO}	SDO Data Valid Delay from SCK \uparrow	$C_L = 20\text{pF}$, $OV_{DD} = 5.25\text{V}$	●		7.5	ns
		$C_L = 20\text{pF}$, $OV_{DD} = 2.5\text{V}$	●		8	ns
		$C_L = 20\text{pF}$, $OV_{DD} = 1.71\text{V}$	●		9.5	ns
t_{HSDO}	SDO Data Remains Valid Delay from SCK \uparrow	$C_L = 20\text{pF}$ (Note 11)	●	1		ns
$t_{DSDOBUSYL}$	SDO Data Valid Delay from BUSY \downarrow	$C_L = 20\text{pF}$ (Note 11)	●		5	ns
t_{EN}	Bus Enable Time After RDL \downarrow	(Note 12)	●		16	ns
t_{DIS}	Bus Relinquish Time After RDL \uparrow	(Note 12)	●		13	ns
t_{WAKE}	REFBUF Wake-Up Time	$C_{REFBUF} = 47\mu\text{F}$, $C_{REFIN} = 100\text{nF}$			200	ms

ELECTRICAL CHARACTERISTICS

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: All voltage values are with respect to ground.

Note 3: When these pin voltages are taken below ground or above V_{DD} or OV_{DD} , they will be clamped by internal diodes. This product can handle input currents up to 100mA below ground or above V_{DD} or OV_{DD} without latch-up.

Note 4: $V_{DD} = 5V$, $OV_{DD} = 2.5V$, $\pm 10.24V$ Range, $REFIN = 2.048V$, $f_{SMPL} = 250kHz$.

Note 5: Recommended operating conditions.

Note 6: Integral nonlinearity is defined as the deviation of a code from a straight line passing through the actual endpoints of the transfer curve. The deviation is measured from the center of the quantization band.

Note 7: Bipolar zero error is the offset voltage measured from $-0.5LSB$ when the output code flickers between 0000 0000 0000 0000 and 1111 1111 1111 1111. Full-scale bipolar error is the worst-case of $-FS$ or $+FS$ untrimmed deviation from ideal first and last code transitions and includes the effect of offset error.

Note 8: All specifications in dB are referred to a full-scale $\pm 10.24V$ input with $REFIN = 2.048V$.

Note 9: When $REFBUF$ is overdriven, the internal reference buffer must be turned off by setting $REFIN = 0V$.

Note 10: $f_{SMPL} = 250kHz$, I_{REFBUF} varies proportionally with sample rate.

Note 11: Guaranteed by design, not subject to test.

Note 12: Parameter tested and guaranteed at $OV_{DD} = 1.71V$, $OV_{DD} = 2.5V$ and $OV_{DD} = 5.25V$.

Note 13: t_{SCK} of 10ns maximum allows a shift clock frequency up to 100MHz for rising edge capture.

Note 14: Temperature coefficient is calculated by dividing the maximum change in output voltage by the specified temperature range.

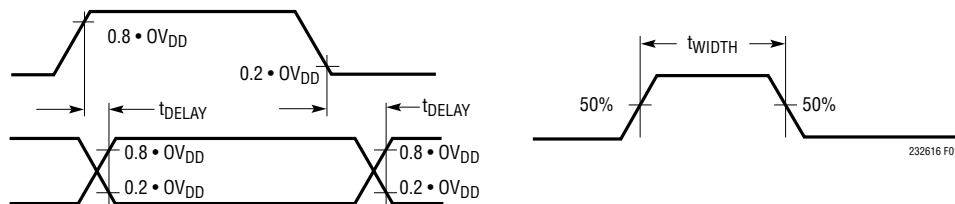
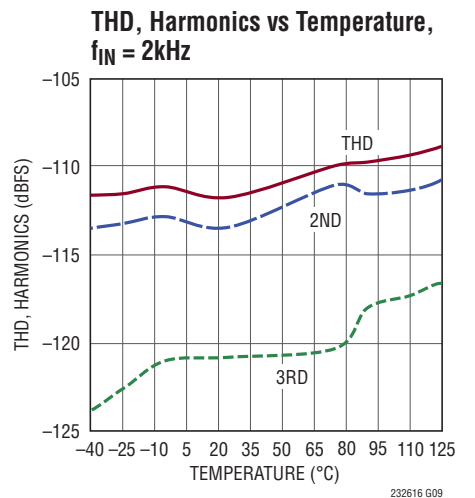
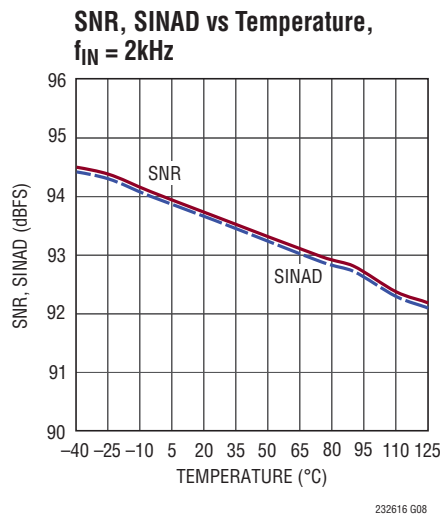
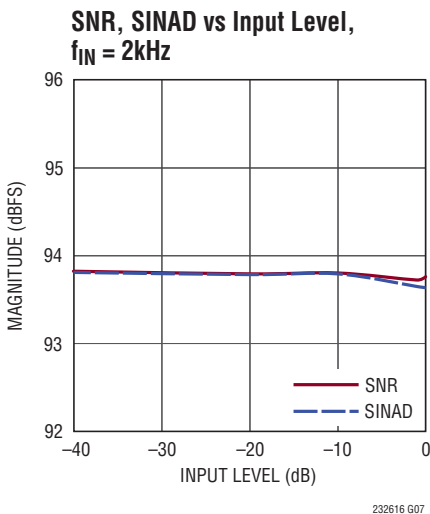
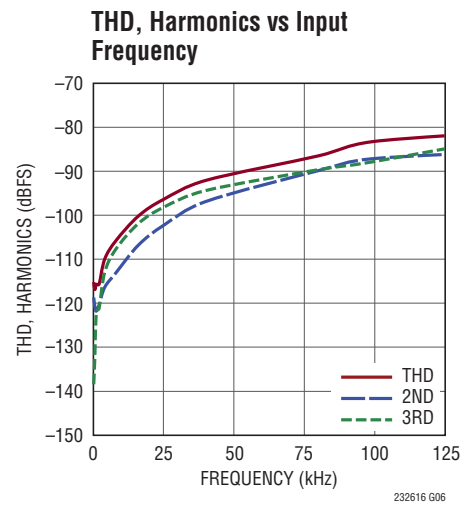
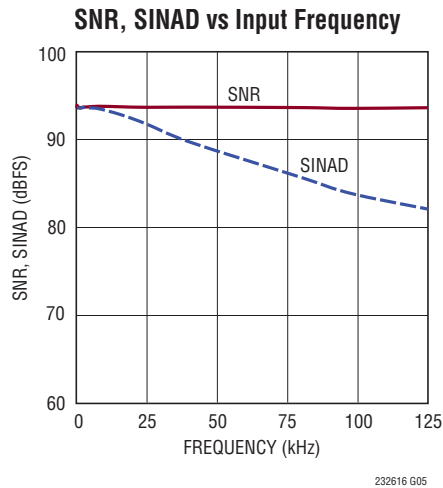
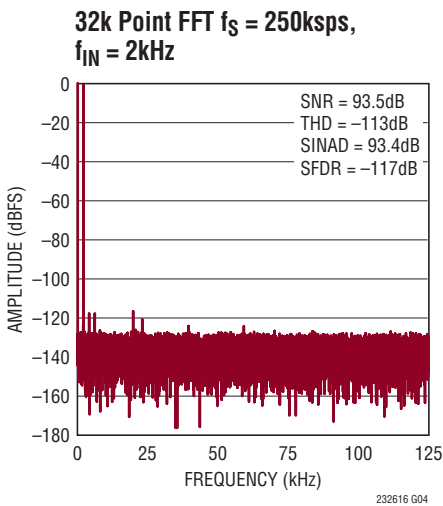
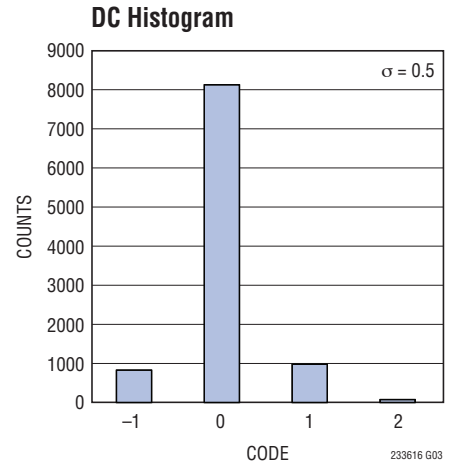
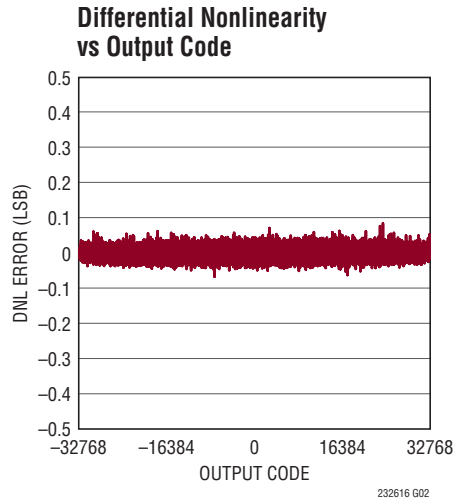
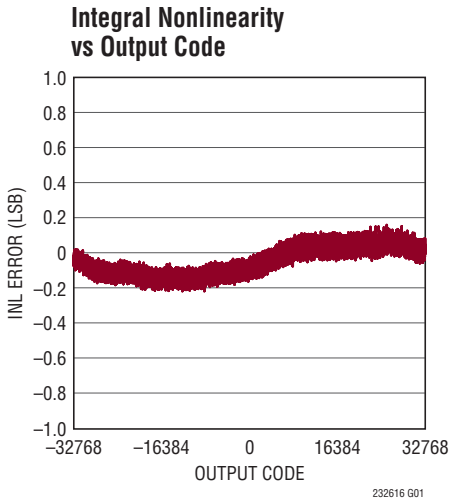


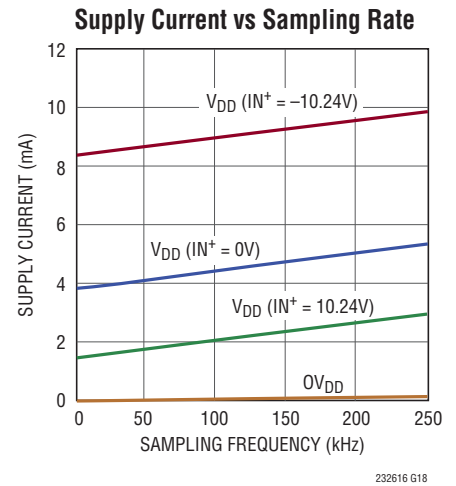
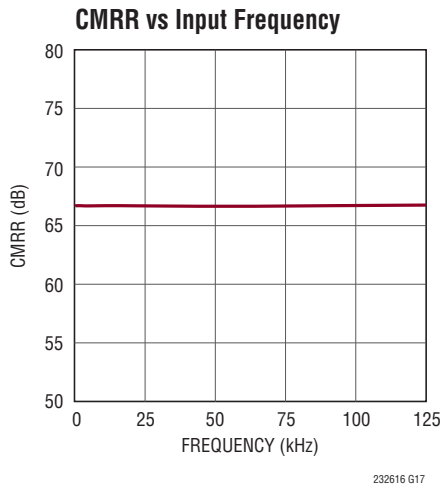
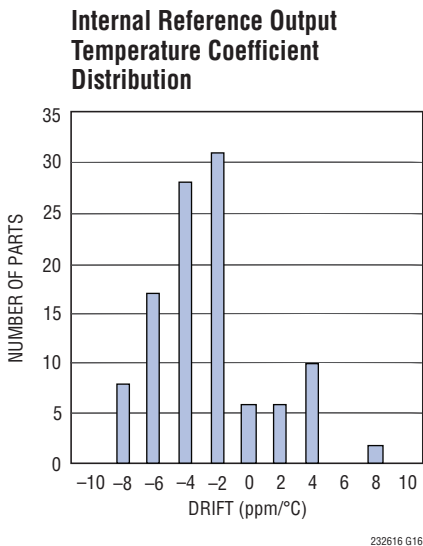
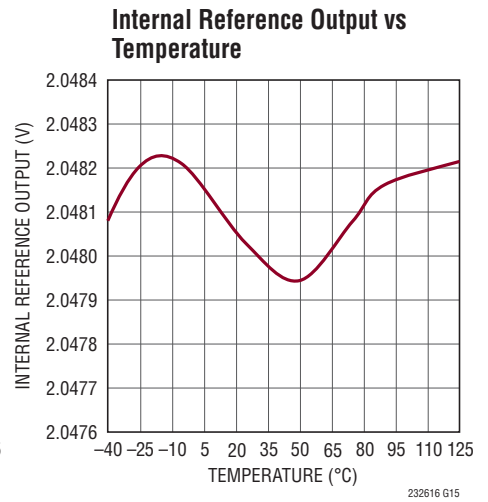
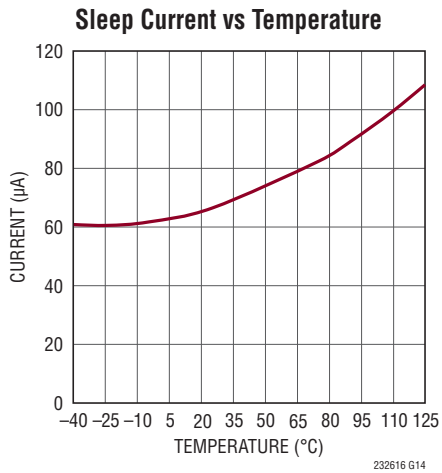
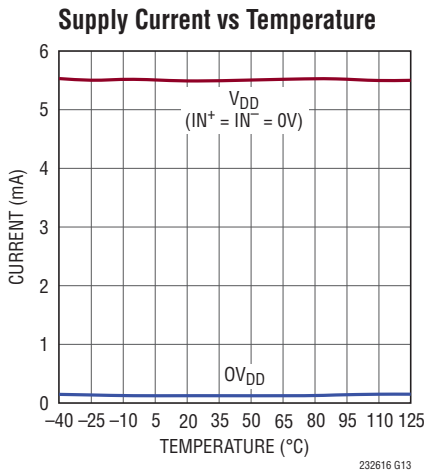
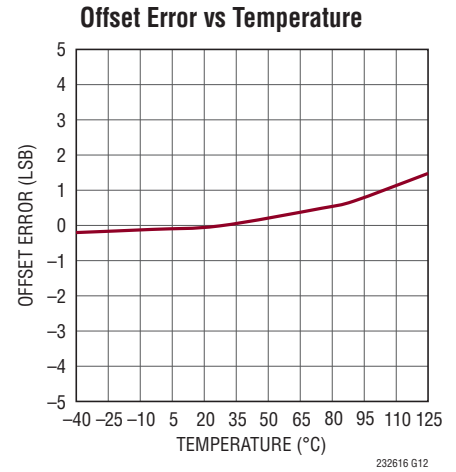
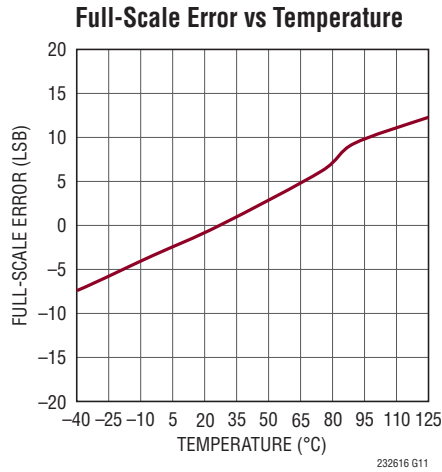
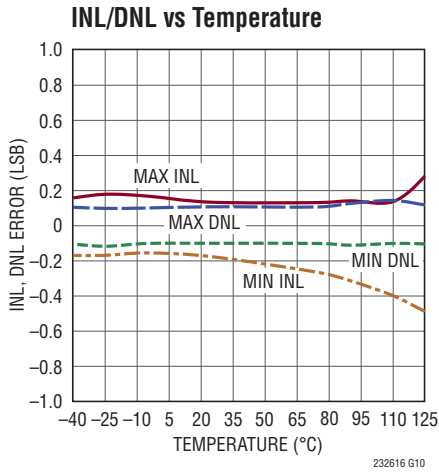
Figure 1. Voltage Levels for Timing Specifications

TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $0V_{DD} = 2.5\text{V}$, $REFIN = 2.048\text{V}$, $f_{SAMPL} = 250\text{ksps}$, unless otherwise noted.



LTC2326-16

TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $OV_{DD} = 2.5\text{V}$, $REF_{IN} = 2.048\text{V}$, $f_{SAMPL} = 250\text{ksps}$, unless otherwise noted.



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PIN FUNCTIONS

V_{DDL}BYP (Pin 1): 2.5V Supply Bypass Pin. The voltage on this pin is generated via an onboard regulator off of V_{DD}. This pin must be bypassed with a 2.2μF ceramic capacitor to GND.

V_{DD} (Pin 2): 5V Power Supply. The range of V_{DD} is 4.75V to 5.25V. Bypass V_{DD} to GND with a 10μF ceramic capacitor.

GND (Pins 3, 6 and 16): Ground.

IN⁺ (Pin 4): Analog Input. IN⁺ operates differential with respect to IN⁻ with an IN⁺-IN⁻ range of $-2.5 \cdot V_{REFBUF}$ to $2.5 \cdot V_{REFBUF}$.

IN⁻ (Pin 5): Analog Ground Sense. IN⁻ has an input range of $\pm 500\text{mV}$ with respect to GND and must be tied to the ground plane or a remote sense.

REFBUF (Pin 7): Reference Buffer Output. An onboard buffer nominally outputs 4.096V to this pin. This pin is referred to GND and should be decoupled closely to the pin with a 47μF ceramic capacitor. The internal buffer driving this pin may be disabled by grounding its input at REFIN. Once the buffer is disabled, an external reference may overdrive this pin in the range of 2.5V to 5V. A resistive load greater than 500kΩ can be placed on the reference buffer output.

REFIN (Pin 8): Reference Output/Reference Buffer Input. An onboard bandgap reference nominally outputs 2.048V at this pin. Bypass this pin with a 100nF ceramic capacitor to GND to limit the reference output noise. If more accuracy is desired, this pin may be overdriven by an external reference in the range of 1.25V to 2.4V.

CNV (Pin 9): Convert Input. A rising edge on this input powers up the part and initiates a new conversion. Logic levels are determined by OV_{DD}.

CHAIN (Pin 10): Chain Mode Selector Pin. When low, the LTC2326-16 operates in normal mode and the RDL/SDI input pin functions to enable or disable SDO. When high, the LTC2326-16 operates in chain mode and the RDL/SDI pin functions as SDI, the daisy-chain serial data input. Logic levels are determined by OV_{DD}.

BUSY (Pin 11): BUSY Indicator. Goes high at the start of a new conversion and returns low when the conversion has finished. Logic levels are determined by OV_{DD}.

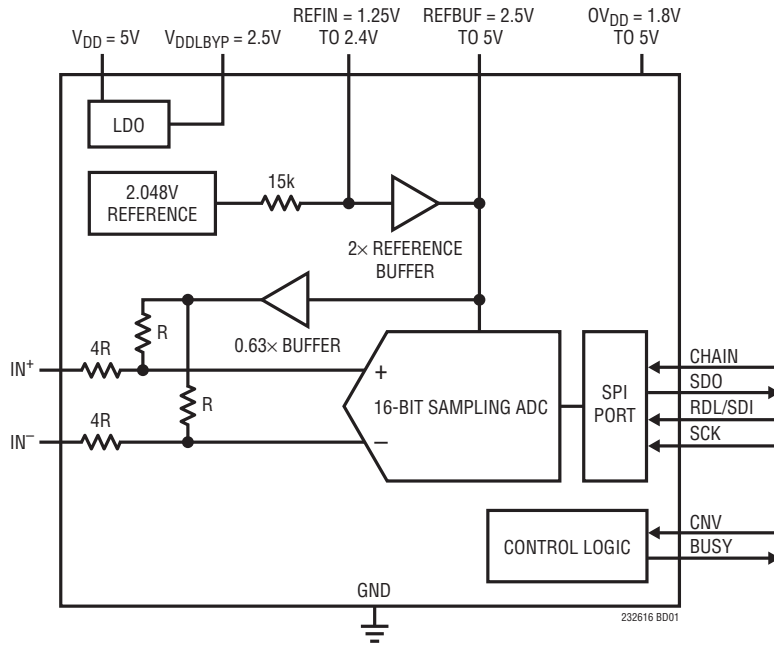
RDL/SDI (Pin 12): When CHAIN is low, the part is in normal mode and the pin is treated as a bus enabling input. When CHAIN is high, the part is in chain mode and the pin is treated as a serial data input pin where data from another ADC in the daisy chain is input. Logic levels are determined by OV_{DD}.

SCK (Pin 13): Serial Data Clock Input. When SDO is enabled, the conversion result or daisy-chain data from another ADC is shifted out on the rising edges of this clock MSB first. Logic levels are determined by OV_{DD}.

SDO (Pin 14): Serial Data Output. The conversion result or daisy-chain data is output on this pin on each rising edge of SCK MSB first. The output data is in 2's complement format. Logic levels are determined by OV_{DD}.

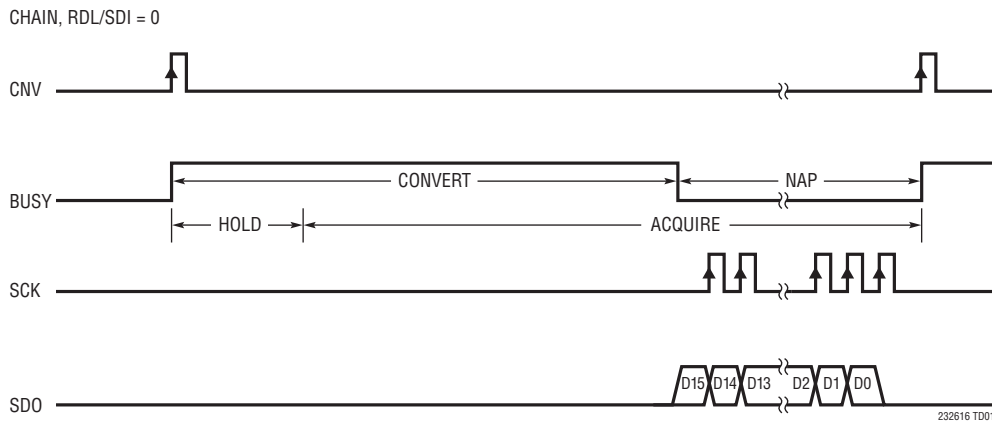
OV_{DD} (Pin 15): I/O Interface Digital Power. The range of OV_{DD} is 1.71V to 5.25V. This supply is nominally set to the same supply as the host interface (1.8V, 2.5V, 3.3V, or 5V). Bypass OV_{DD} to GND with a 0.1μF capacitor.

FUNCTIONAL BLOCK DIAGRAM



TIMING DIAGRAM

Conversion Timing Using the Serial Interface



APPLICATIONS INFORMATION

OVERVIEW

The LTC2326-16 is a low noise, high speed 16-bit successive approximation register (SAR) ADC with pseudo-differential inputs. Operating from a single 5V supply, the LTC2326-16 has a $\pm 10.24\text{V}$ true bipolar input range, making it ideal for high voltage applications which require a wide dynamic range. The LTC2326-16 achieves $\pm 1.5\text{LSB}$ INL maximum, no missing codes at 16-bits and 93.5dB SNR.

The LTC2326-16 has an onboard single-shot capable reference buffer and low drift (20ppm/ $^{\circ}\text{C}$ max) 2.048V temperature-compensated reference. The LTC2326-16 also has a high speed SPI-compatible serial interface that supports 1.8V, 2.5V, 3.3V and 5V logic while also featuring a daisy-chain mode. The fast 250ksps throughput with no cycle latency makes the LTC2326-16 ideally suited for a wide variety of high speed applications. An internal oscillator sets the conversion time, easing external timing considerations. The LTC2326-16 dissipates only 28mW and automatically naps between conversions, leading to reduced power dissipation that scales with the sampling rate. A sleep mode is also provided to reduce the power consumption of the LTC2326-16 to 300 μW for further power savings during inactive periods.

CONVERTER OPERATION

The LTC2326-16 operates in two phases. During the acquisition phase, the charge redistribution capacitor D/A converter (CDAC) is connected to the outputs of the resistor divider networks that pins IN^+ and IN^- drive to sample an attenuated and level-shifted version of the pseudo-differential analog input voltage as shown in Figure 3. A rising edge on the CNV pin initiates a conversion. During the conversion phase, the 16-bit CDAC is sequenced through a successive approximation algorithm, effectively comparing the sampled input with binary-weighted fractions of the reference voltage (e.g. $V_{\text{REFBUF}}/2$, $V_{\text{REFBUF}}/4$... $V_{\text{REFBUF}}/65536$) using the differential comparator. At the end of conversion, the CDAC output approximates the sampled analog input. The ADC control logic then prepares the 16-bit digital output code for serial transfer.

TRANSFER FUNCTION

The LTC2326-16 digitizes the full-scale voltage of $\pm 2.5 \cdot \text{REFBUF}$ into 2^{16} levels, resulting in an LSB size of 312.5 μV with $\text{REFBUF} = 4.096\text{V}$. The ideal transfer function is shown in Figure 2. The output data is in 2's complement format.

ANALOG INPUT

The analog inputs of the LTC2326-16 are pseudo-differential in order to reduce any unwanted signal that is common to both inputs. The analog inputs can be modeled by the equivalent circuit shown in Figure 3. The back-to-back diodes at the inputs form clamps that provide ESD protection. Each input drives a resistor divider network that has

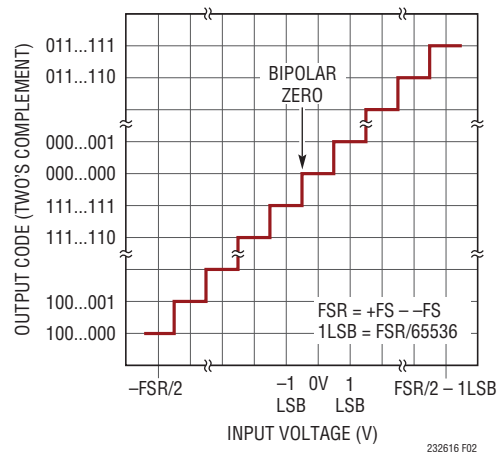


Figure 2. LTC2326-16 Transfer Function

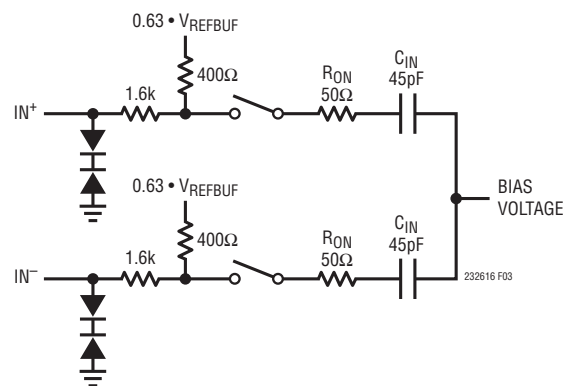


Figure 3. The Equivalent Circuit for the Differential Analog Input of the LTC2326-16

APPLICATIONS INFORMATION

a total impedance of $2k\Omega$. The resistor divider network attenuates and level shifts the $\pm 2.5 \cdot \text{REFBUF}$ true bipolar signal swing of each input to the 0-REFBUF input signal swing of the ADC core. In the acquisition phase, 45pF (C_{IN}) from the sampling CDAC in series with approximately 50Ω (R_{ON}) from the on-resistance of the sampling switch is connected to the output of the resistor divider network. Any unwanted signal that is common to both inputs will be reduced by the common mode rejection of the ADC core and resistor divider network. The IN^+ input of the ADC core draws a current spike while charging the C_{IN} capacitor during acquisition.

INPUT DRIVE CIRCUITS

A low impedance source can directly drive the high impedance input of the LTC2326-16 without gain error. A high impedance source should be buffered to minimize settling time during acquisition and to optimize the distortion performance of the ADC. Minimizing settling time is important even for DC inputs, because the ADC input draws a current spike when entering acquisition.

For best performance, a buffer amplifier should be used to drive the analog input of the LTC2326-16. The amplifier provides low output impedance to minimize gain error and allows for fast settling of the analog signal during the acquisition phase. It also provides isolation between the signal source and the ADC input which draws a small current spike during acquisition.

Input Filtering

The noise and distortion of the buffer amplifier and signal source must be considered since they add to the ADC noise and distortion. Noisy input signals should be filtered prior to the buffer amplifier input with a low bandwidth filter to minimize noise. The simple 1-pole RC lowpass filter shown in Figure 4 is sufficient for many applications.

The input resistor divider network, sampling switch on-resistance (R_{ON}) and the sample capacitor (C_{IN}) form a second lowpass filter that limits the input bandwidth to the ADC core to 7MHz . A buffer amplifier with a low noise density must be selected to minimize the degradation of the SNR over this bandwidth.

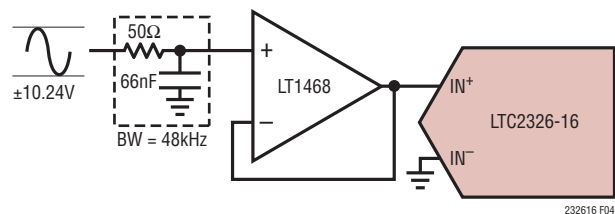


Figure 4. Input Signal Chain

High quality capacitors and resistors should be used in the RC filters since these components can add distortion. NPO and silver mica type dielectric capacitors have excellent linearity. Carbon surface mount resistors can generate distortion from self heating and from damage that may occur during soldering. Metal film surface mount resistors are much less susceptible to both problems.

Pseudo-Differential Bipolar Inputs

For most applications, we recommend the low power LT1468 ADC driver to drive the LTC2326-16. With a low noise density of $5\text{nV}/\sqrt{\text{Hz}}$ and a low supply current of 3mA , the LT1468 is flexible and may be configured to convert signals of various amplitudes to the $\pm 10.24\text{V}$ input range of the LTC2326-16.

To achieve the full distortion performance of the LTC2326-16, a low distortion single-ended signal source driven through the LT1468 configured as a unity-gain buffer as shown in Figure 4 can be used to get the full data sheet THD specification of -111dB .

ADC REFERENCE

There are three ways of providing the ADC reference. The first is to use both the internal reference and reference buffer. The second is to externally overdrive the internal reference and use the internal reference buffer. The third is to disable the internal reference buffer and overdrive the REFBUF pin from an external source. The following tables give examples of these cases and the resulting bipolar input ranges.

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Table 1. Internal Reference with Internal Buffer

REFIN	REFBUF	BIPOLAR INPUT RANGE
2.048V	4.096V	$\pm 10.24V$

Table 2. External Reference with Internal Buffer

REFIN (OVERDRIVE)	REFBUF	BIPOLAR INPUT RANGE
1.25V (Min)	2.5V	$\pm 6.25V$
2.048V	4.096V	$\pm 10.24V$
2.4V (Max)	4.8V	$\pm 12V$

Table 3. External Reference Unbuffered

REFIN	REFBUF (OVERDRIVE)	BIPOLAR INPUT RANGE
0V	2.5V (Min)	$\pm 6.25V$
0V	5V (Max)	$\pm 12.5V$

Internal Reference with Internal Buffer

The LTC2326-16 has an on-chip, low noise, low drift (20ppm/°C max), temperature compensated bandgap reference that is factory trimmed to 2.048V. It is internally connected to a reference buffer as shown in Figure 5a and is available at REFIN (Pin 8). REFIN should be bypassed to GND with a 100nF ceramic capacitor to minimize noise. The reference buffer gains the REFIN voltage by 2 to 4.096V at REFBUF (Pin 7). So the input range is $\pm 10.24V$, as shown in Table 1. Bypass REFBUF to GND with at least a 47 μ F ceramic capacitor (X7R, 10V, 1210 size) to compensate the reference buffer and minimize noise.

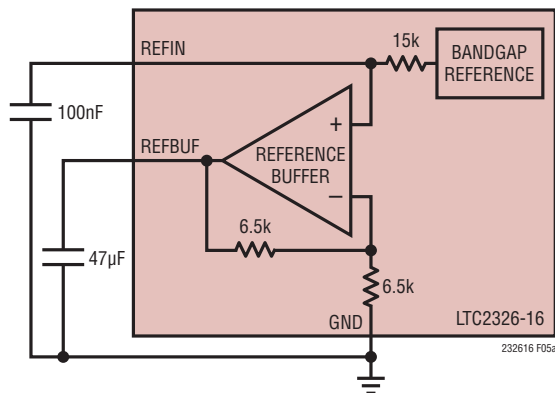


Figure 5a. LTC2326-16 Internal Reference Circuit

External Reference with Internal Buffer

If more accuracy and/or lower drift is desired, REFIN can be easily overdriven by an external reference since a 15k resistor is in series with the reference as shown in Figure 5b. REFIN can be overdriven in the range from 1.25V to 2.4V. The resulting voltage at REFBUF will be $2 \cdot \text{REFIN}$. So the input range is $\pm 5 \cdot \text{REFIN}$, as shown in Table 2. Linear Technology offers a portfolio of high performance references designed to meet the needs of many applications. With its small size, low power, and high accuracy, the LTC6655-2.048 is well suited for use with the LTC2326-16 when overdriving the internal reference. The LTC6655-2.048 offers 0.025% (max) initial accuracy and 2ppm/°C (max) temperature coefficient for high precision applications. The LTC6655-2.048 is fully specified over the H-grade temperature range and complements the extended temperature range of the LTC2326-16 up to 125°C. Bypassing the LTC6655-2.048 with a 2.7 μ F to 100 μ F ceramic capacitor close to the REFIN pin is recommended.

External Reference Unbuffered

The internal reference buffer can also be overdriven from 2.5V to 5V with an external reference at REFBUF as shown in Figure 5c. So the input ranges are $\pm 6.25V$ to $\pm 12.5V$, respectively, as shown in Table 3. To do so, REFIN must be grounded to disable the reference buffer. A 13k resistor loads the REFBUF pin when the reference buffer is disabled. To maximize the input signal swing and corresponding SNR, the LTC6655-5 is recommended when overdriving REFBUF. The LTC6655-5 offers the same small size, accuracy, drift and extended temperature range as the LTC6655-2.048. By using this 5V reference, an SNR of 94.5dB can be achieved. Bypassing the LTC6655-5 with a 47 μ F ceramic capacitor (X5R, 0805 size) close to the REFBUF pin is recommended.

The REFBUF pin of the LTC2326-16 draws a charge (Q_{CONV}) from the external bypass capacitor during each conversion cycle. If the internal reference buffer is overdriven, the external reference must provide all of this charge with a DC current equivalent to $I_{\text{REFBUF}} = Q_{\text{CONV}}/t_{\text{CYC}}$. Thus, the DC current draw of REFBUF depends on the sampling

APPLICATIONS INFORMATION

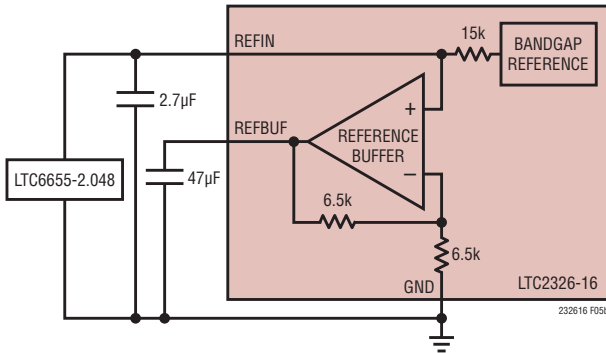


Figure 5b. Using the LTC6655-2.048 as an External Reference

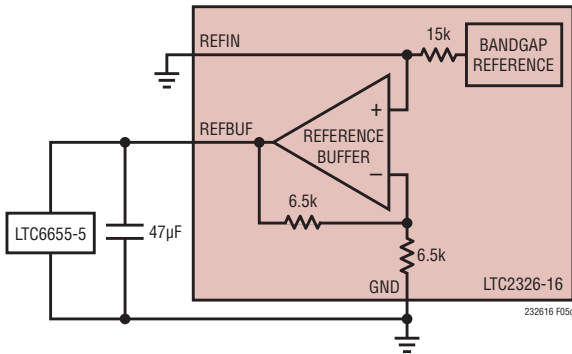


Figure 5c. Overdriving REFBUF Using the LTC6655-5

rate and output code. In applications where a burst of samples is taken after idling for long periods, as shown in Figure 6, I_{REFBUF} quickly goes from approximately $390\mu\text{A}$ to a maximum of 0.6mA for $REFBUF = 5\text{V}$ at 250kps . This step in DC current draw triggers a transient response in the external reference that must be considered since any deviation in the voltage at REFBUF will affect the accuracy

of the output code. If an external reference is used to overdrive REFBUF, the fast settling LTC6655-5 reference is recommended.

Internal Reference Buffer Transient Response

For optimum transient performance, the internal reference buffer should be used. The internal reference buffer uses a proprietary design that results in an output voltage change at REFBUF of less than 0.25LSB when responding to a sudden burst of conversions. This makes the internal reference buffer of the LTC2326-16 truly single-shot capable since the first sample taken after idling will yield the same result as a sample taken after the transient response of the internal reference buffer has settled. Figure 7 shows the transient responses of the LTC2326-16 with the internal reference buffer and with the internal reference buffer overdriven by the LTC6655-5, both with a bypass capacitance of $47\mu\text{F}$.

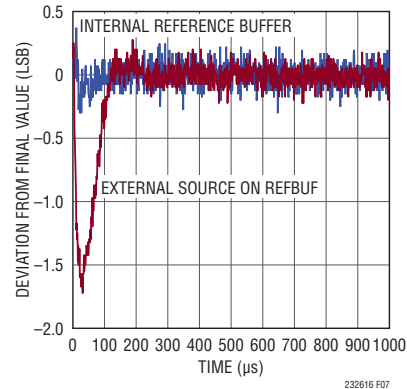


Figure 7. Transient Response of the LTC2326-16

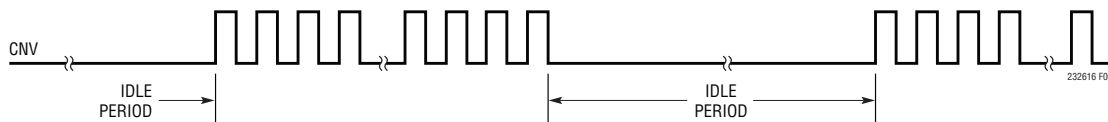


Figure 6. CNV Waveform Showing Burst Sampling

APPLICATIONS INFORMATION

DYNAMIC PERFORMANCE

Fast Fourier Transform (FFT) techniques are used to test the ADC's frequency response, distortion and noise at the rated throughput. By applying a low distortion sine wave and analyzing the digital output using an FFT algorithm, the ADC's spectral content can be examined for frequencies outside the fundamental. The LTC2326-16 provides guaranteed tested limits for both AC distortion and noise measurements.

Signal-to-Noise and Distortion Ratio (SINAD)

The signal-to-noise and distortion ratio (SINAD) is the ratio between the RMS amplitude of the fundamental input frequency and the RMS amplitude of all other frequency components at the A/D output. The output is band limited to frequencies from above DC and below half the sampling frequency. Figure 8 shows that the LTC2326-16 achieves a typical SINAD of 93.4dB at a 250kHz sampling rate with a 2kHz input.

Signal-to-Noise Ratio (SNR)

The signal-to-noise ratio (SNR) is the ratio between the RMS amplitude of the fundamental input frequency and the RMS amplitude of all other frequency components except the first five harmonics and DC. Figure 8 shows that the LTC2326-16 achieves a typical SNR of 93.5dB at a 250kHz sampling rate with a 2kHz input.

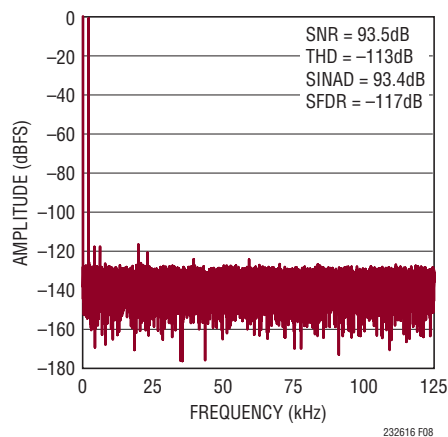


Figure 8. 32k Point FFT of the LTC2326-16

Total Harmonic Distortion (THD)

Total Harmonic Distortion (THD) is the ratio of the RMS sum of all harmonics of the input signal to the fundamental itself. The out-of-band harmonics alias into the frequency band between DC and half the sampling frequency ($f_{\text{SAMPL}}/2$). THD is expressed as:

$$\text{THD} = 20 \log \frac{\sqrt{V_2^2 + V_3^2 + V_4^2 + \dots + V_N^2}}{V_1}$$

where V_1 is the RMS amplitude of the fundamental frequency and V_2 through V_N are the amplitudes of the second through Nth harmonics.

POWER CONSIDERATIONS

The LTC2326-16 provides two power supply pins: the 5V power supply (V_{DD}), and the digital input/output interface power supply (OV_{DD}). The flexible OV_{DD} supply allows the LTC2326-16 to communicate with any digital logic operating between 1.8V and 5V, including 2.5V and 3.3V systems.

Power Supply Sequencing

The LTC2326-16 does not have any specific power supply sequencing requirements. Care should be taken to adhere to the maximum voltage relationships described in the Absolute Maximum Ratings section. The LTC2326-16 has a power-on reset (POR) circuit that will reset the LTC2326-16 at initial power-up or whenever the power supply voltage drops below 2V. Once the supply voltage reenters the nominal supply voltage range, the POR will re-initialize the ADC. No conversions should be initiated until 200 μ s after a POR event to ensure the re-initialization period has ended. Any conversions initiated before this time will produce invalid results.

TIMING AND CONTROL

CNV Timing

The LTC2326-16 conversion is controlled by CNV. A rising edge on CNV will start a conversion and power up the LTC2326-16. Once a conversion has been initiated,

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it cannot be restarted until the conversion is complete. For optimum performance, CNV should be driven by a clean low jitter signal. Converter status is indicated by the BUSY output which remains high while the conversion is in progress. To ensure that no errors occur in the digitized results, any additional transitions on CNV should occur within 40ns from the start of the conversion or after the conversion has been completed. Once the conversion has completed, the LTC2326-16 powers down.

Acquisition

A proprietary sampling architecture allows the LTC2326-16 to begin acquiring the input signal for the next conversion 527ns after the start of the current conversion. This extends the acquisition time to 3.460 μ s, easing settling requirements and allowing the use of extremely low power ADC drivers. (Refer to the Timing Diagram.)

Internal Conversion Clock

The LTC2326-16 has an internal clock that is trimmed to achieve a maximum conversion time of 3 μ s.

Auto Nap Mode

The LTC2326-16 automatically enters nap mode after a conversion has been completed and completely powers up once a new conversion is initiated on the rising edge of CNV. During nap mode, only the ADC core powers down and all other circuits remain active. During nap, data from the last conversion can be clocked out. The auto nap mode feature will reduce the power dissipation of the LTC2326-16 as the sampling frequency is reduced. Since full power is consumed only during a conversion, the ADC core of the LTC2326-16 remains powered down for a larger fraction of the conversion cycle (t_{CYC}) at lower sample rates, thereby reducing the average power dissipation which scales with the sampling rate as shown in Figure 9.

Sleep Mode

The auto nap mode feature provides limited power savings since only the ADC core powers down. To obtain greater power savings, the LTC2326-16 provides a sleep mode. During sleep mode, the entire part is powered down except for a small standby current resulting in a power

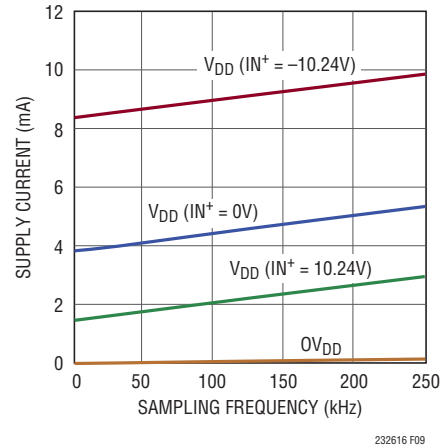


Figure 9. Power Supply Current of the LTC2326-16 Versus Sampling Rate

dissipation of 300 μ W. To enter sleep mode, toggle CNV twice with no intervening rising edge on SCK. The part will enter sleep mode on the falling edge of BUSY from the last conversion initiated. Once in sleep mode, a rising edge on SCK will wake the part up. Upon emerging from sleep mode, wait t_{WAKE} ms before initiating a conversion to allow the reference and reference buffer to wake up and charge the bypass capacitors at REFIN and REFBUF. (Refer to the Timing Diagrams section for more detailed timing information about sleep mode.)

DIGITAL INTERFACE

The LTC2326-16 has a serial digital interface. The flexible O_{VDD} supply allows the LTC2326-16 to communicate with any digital logic operating between 1.8V and 5V, including 2.5V and 3.3V systems.

The serial output data is clocked out on the SDO pin when an external clock is applied to the SCK pin if SDO is enabled. Clocking out the data after the conversion will yield the best performance. With a shift clock frequency of at least 20MHz, a 250ksps throughput is still achieved. The serial output data changes state on the rising edge of SCK and can be captured on the falling edge or next rising edge of SCK. D15 remains valid till the first rising edge of SCK.

The serial interface on the LTC2326-16 is simple and straightforward to use. The following sections describe the operation of the LTC2326-16. Several modes are provided depending on whether a single or multiple ADCs share the SPI bus or are daisy-chained.

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Normal Mode, Single Device

When CHAIN = 0, the LTC2326-16 operates in normal mode. In normal mode, RDL/SDI enables or disables the serial data output pin SDO. If RDL/SDI is high, SDO is in high impedance. If RDL/SDI is low, SDO is driven. Figure 10

shows a single LTC2326-16 operated in normal mode with CHAIN and RDL/SDI tied to ground. With RDL/SDI grounded, SDO is enabled and the MSB(D15) of the new conversion data is available at the falling edge of BUSY. This is the simplest way to operate the LTC2326-16.

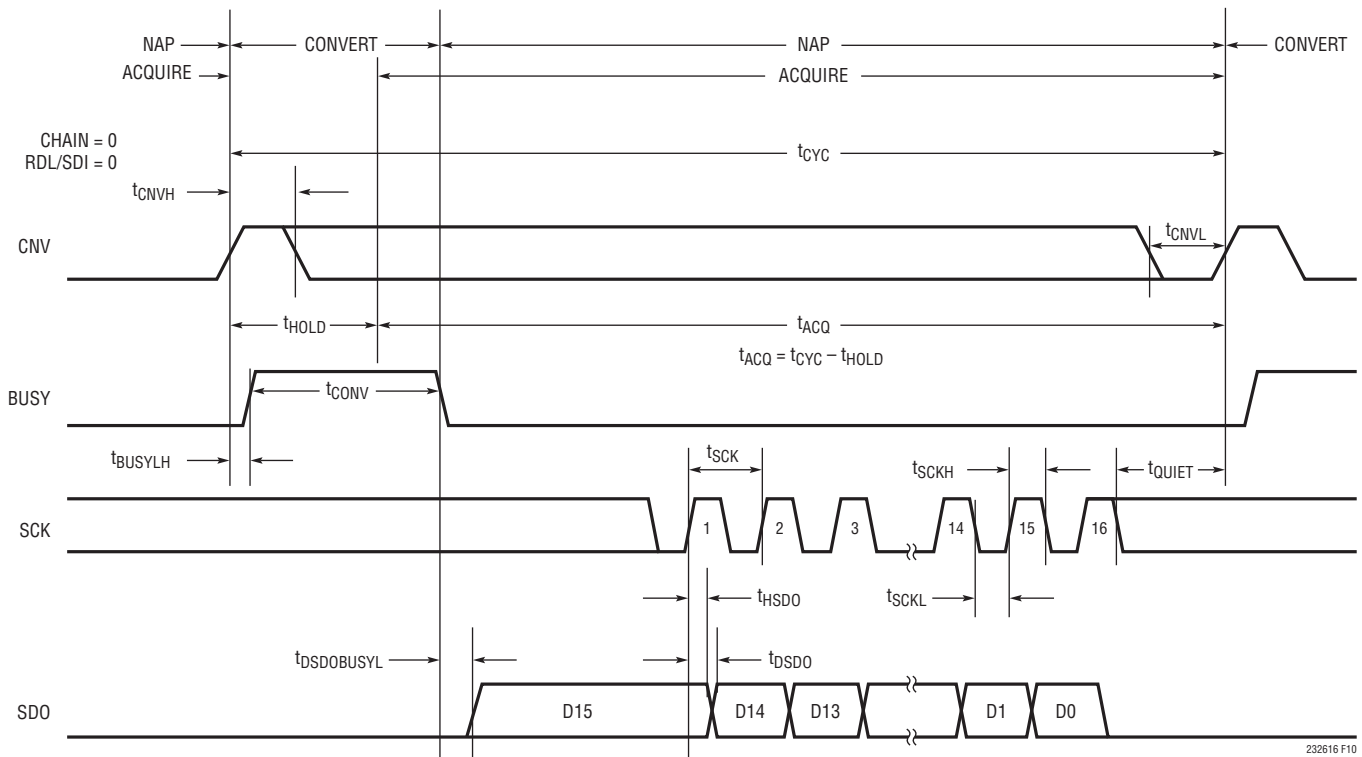
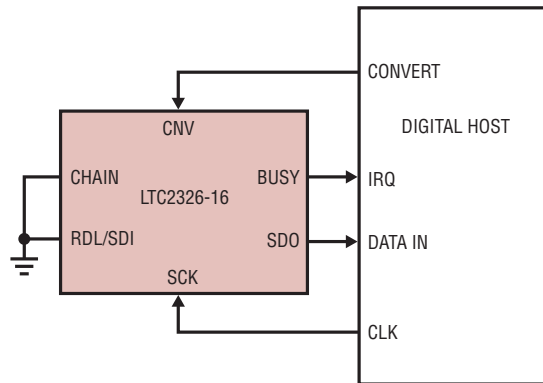


Figure 10. Using a Single LTC2326-16 in Normal Mode

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Normal Mode, Multiple Devices

Figure 11 shows multiple LTC2326-16 devices operating in normal mode (CHAIN = 0) sharing CNV, SCK and SDO. By sharing CNV, SCK and SDO, the number of required signals to operate multiple ADCs in parallel is reduced. Since SDO is shared, the RDL/SDI input of each ADC must

be used to allow only one LTC2326-16 to drive SDO at a time in order to avoid bus conflicts. As shown in Figure 11, the RDL/SDI inputs idle high and are individually brought low to read data out of each device between conversions. When RDL/SDI is brought low, the MSB of the selected device is output onto SDO.

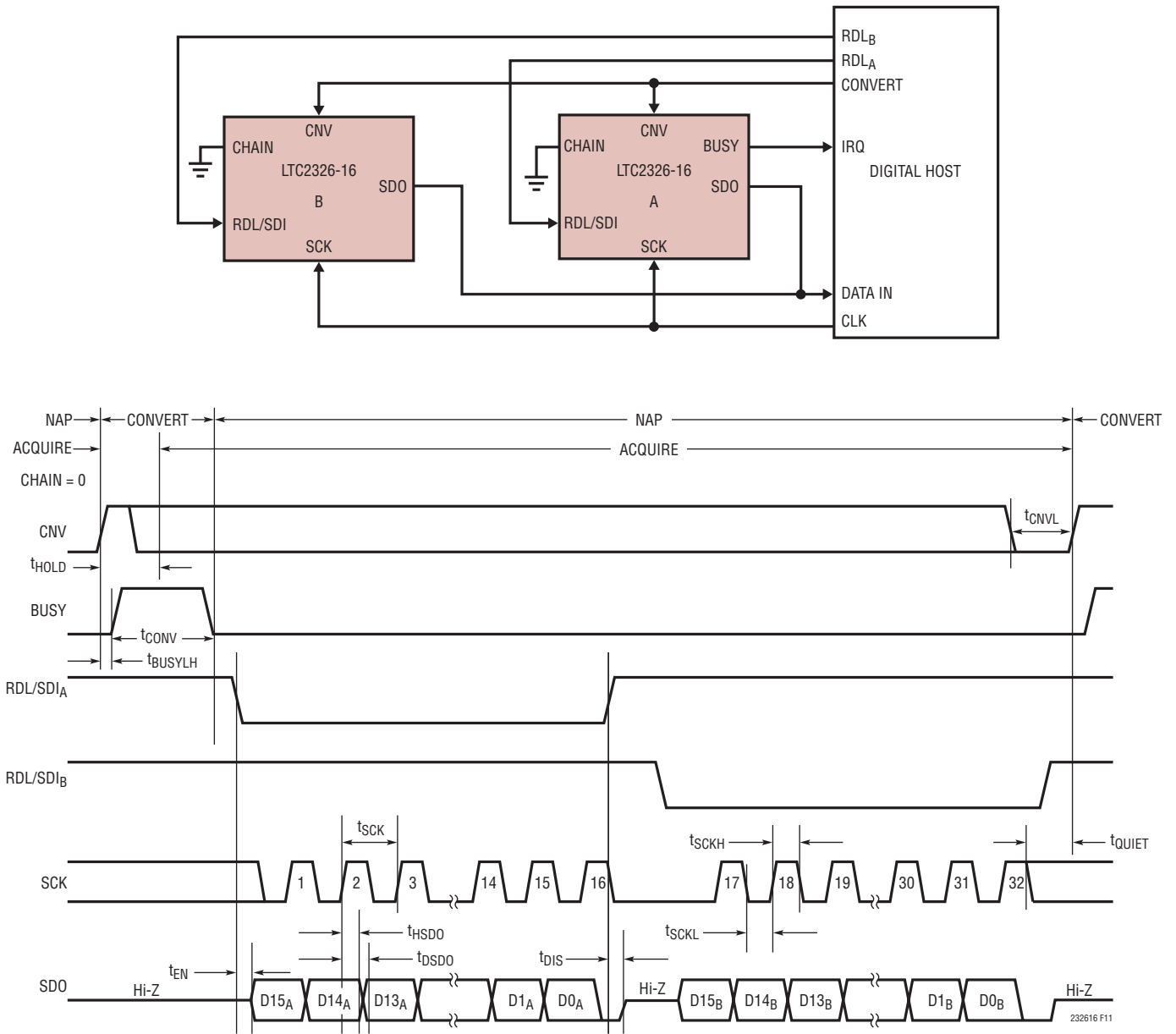


Figure 11. Normal Mode with Multiple Devices Sharing CNV, SCK, and SDO

APPLICATIONS INFORMATION

Chain Mode, Multiple Devices

When CHAIN = OV_{DD} , the LTC2326-16 operates in chain mode. In chain mode, SDO is always enabled and RDL/SDI serves as the serial data input pin (SDI) where daisy-chain data output from another ADC can be input. This is useful for applications where hardware constraints

may limit the number of lines needed to interface to a large number of converters. Figure 12 shows an example with two daisy-chained devices. The MSB of converter A will appear at SDO of converter B after 16 SCK cycles. The MSB of converter A is clocked in at the SDI/RDL pin of converter B on the rising edge of the first SCK.

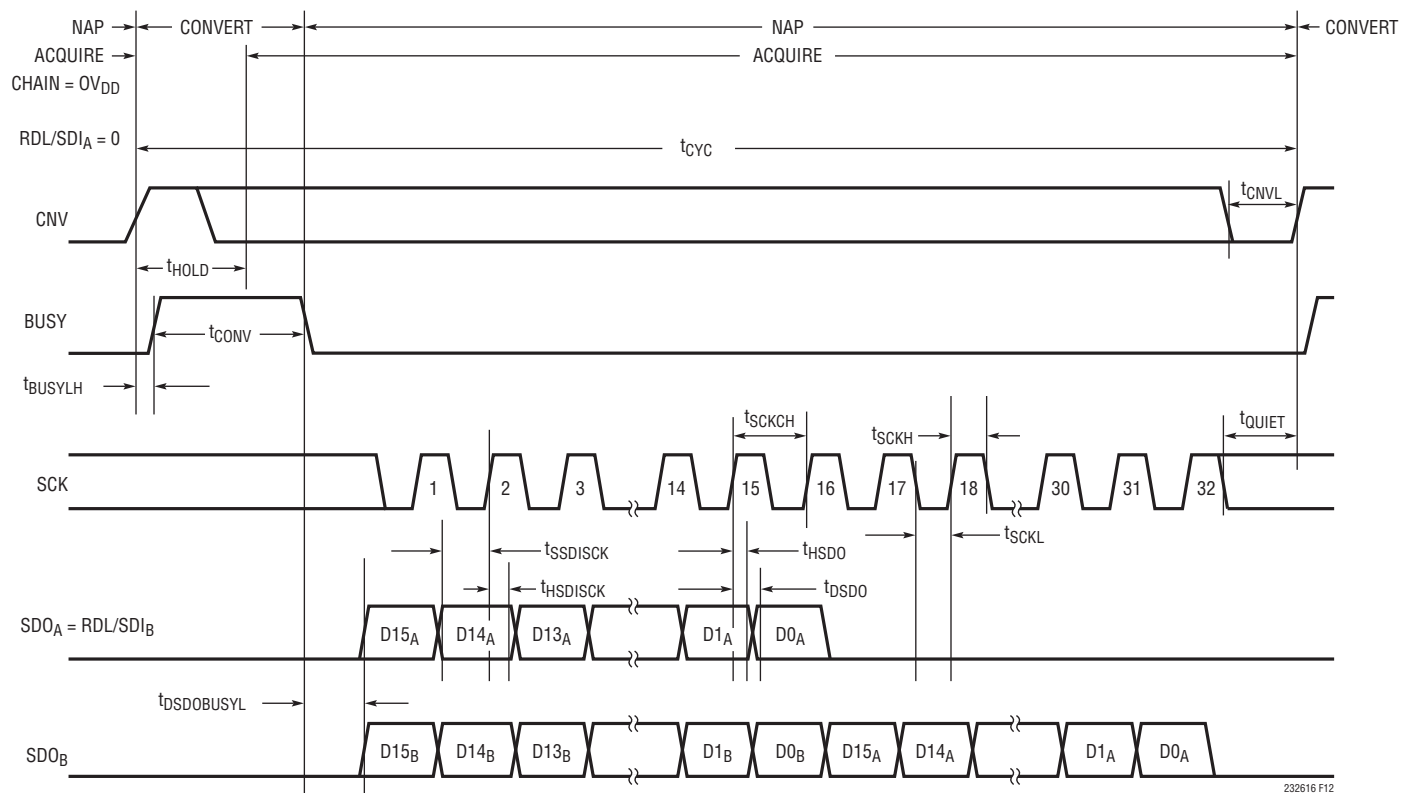
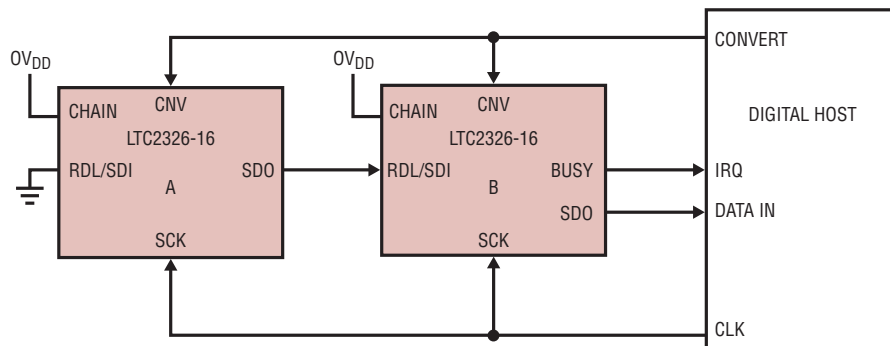


Figure 12. Chain Mode Timing Diagram

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Sleep Mode

To enter sleep mode, toggle CNV twice with no intervening rising edge on SCK as shown in Figure 13. The part will enter sleep mode on the falling edge of BUSY from

the last conversion initiated. Once in sleep mode, a rising edge on SCK will wake the part up. Upon emerging from sleep mode, wait t_{WAKE} ms before initiating a conversion to allow the reference and reference buffer to wake up and charge the bypass capacitors at REFIN and REFBUF.

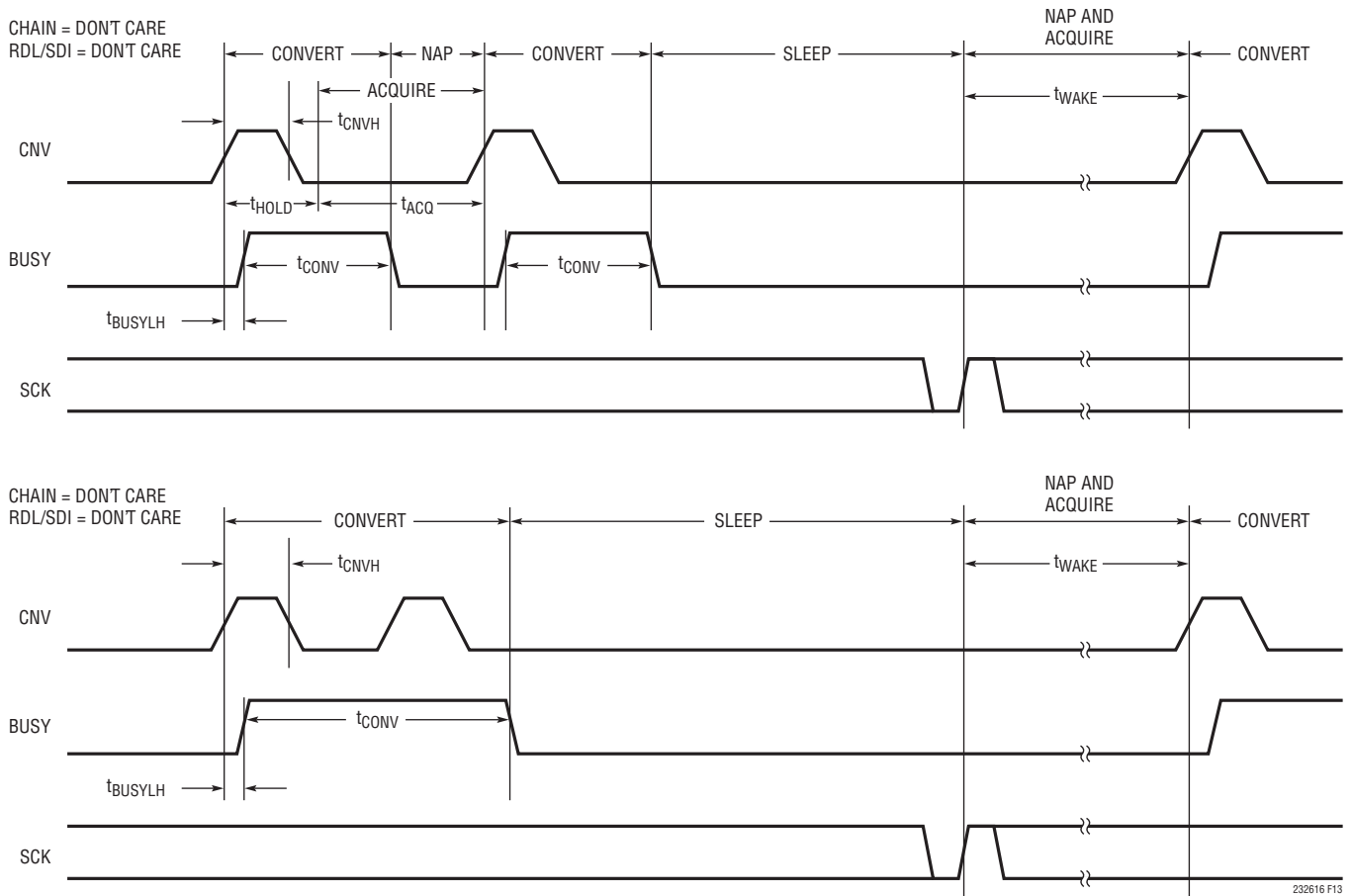


Figure 13. Sleep Mode Timing Diagram

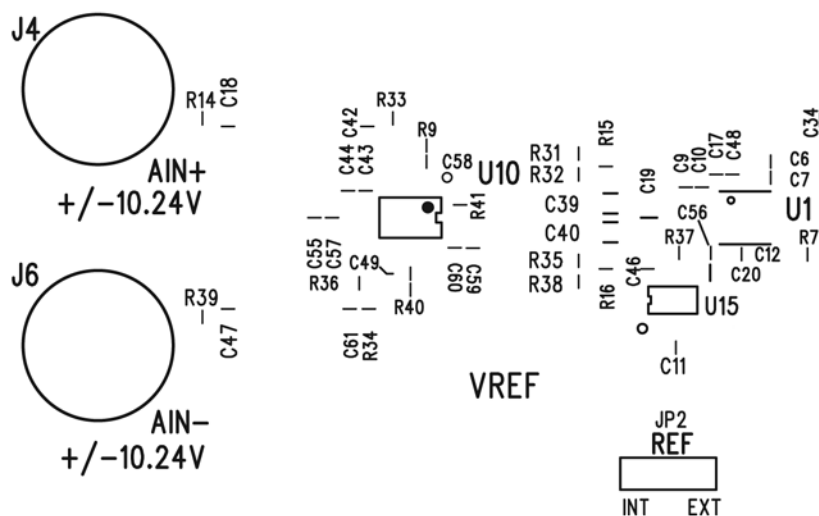
BOARD LAYOUT

To obtain the best performance from the LTC2326-16 a printed circuit board (PCB) is recommended. Layout for PCB should ensure the digital and analog signal lines are separated as much as possible. In particular, care should be taken not to run any digital clocks or signals alongside analog signals or underneath the ADC.

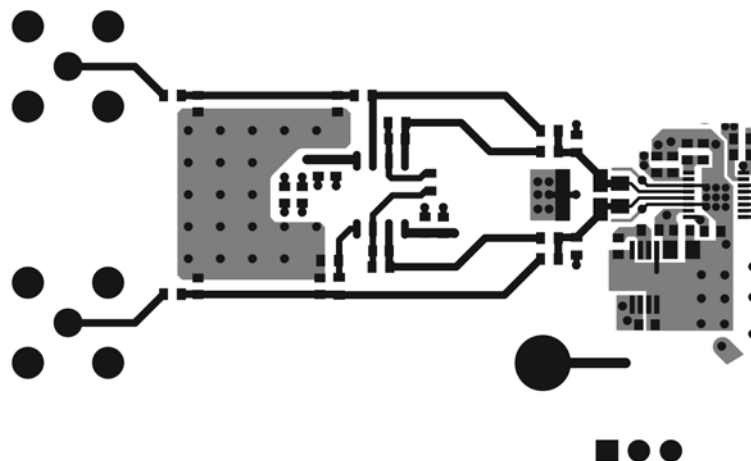
Recommended Layout

The following is an example of a recommended PCB layout. A single solid ground plane is used. Bypass capacitors to the supplies are placed as close as possible to the supply pins. Low impedance common returns for these bypass capacitors are essential to the low noise operation of the ADC. The analog input traces are screened by ground. For more details and information refer to DC1908, the evaluation kit for the LTC2326-16.

Partial Top Silkscreen

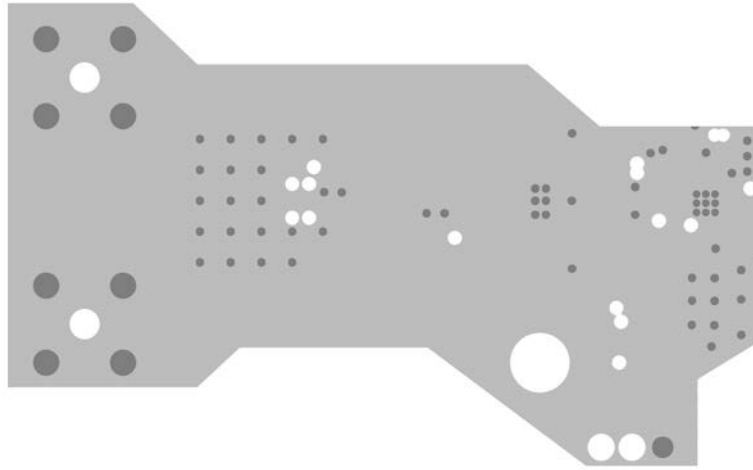


Partial Layer 1 Component Side

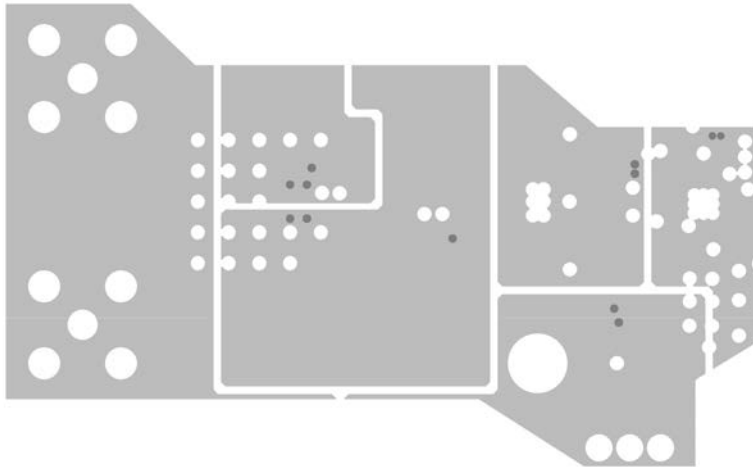


BOARD LAYOUT

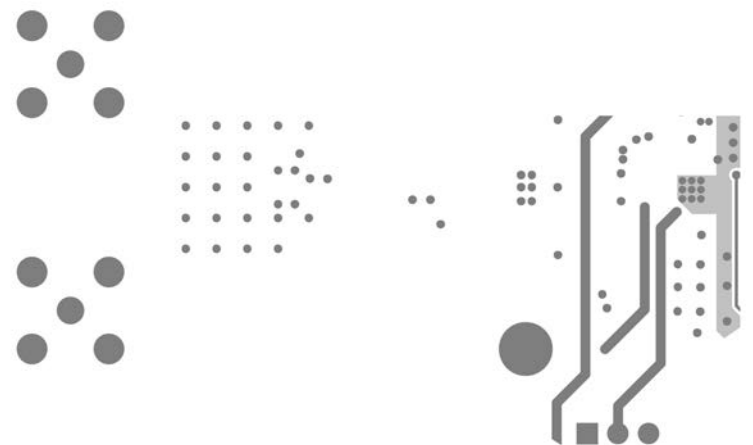
Partial Layer 2 Ground Plane



Partial Layer 3 Power Plane

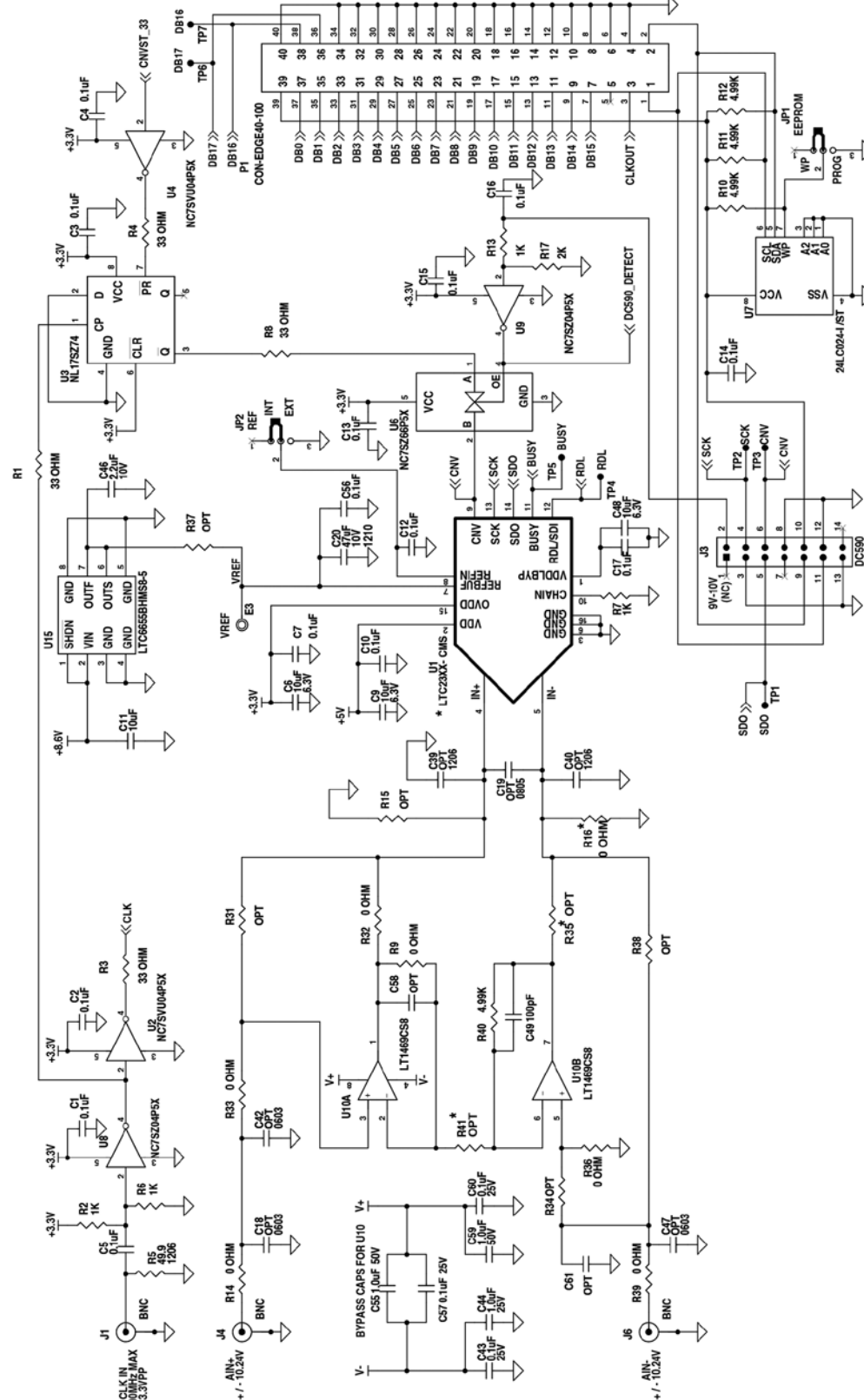


Partial Layer 4 Bottom Layer



BOARD LAYOUT

Partial Schematic of Demo Board



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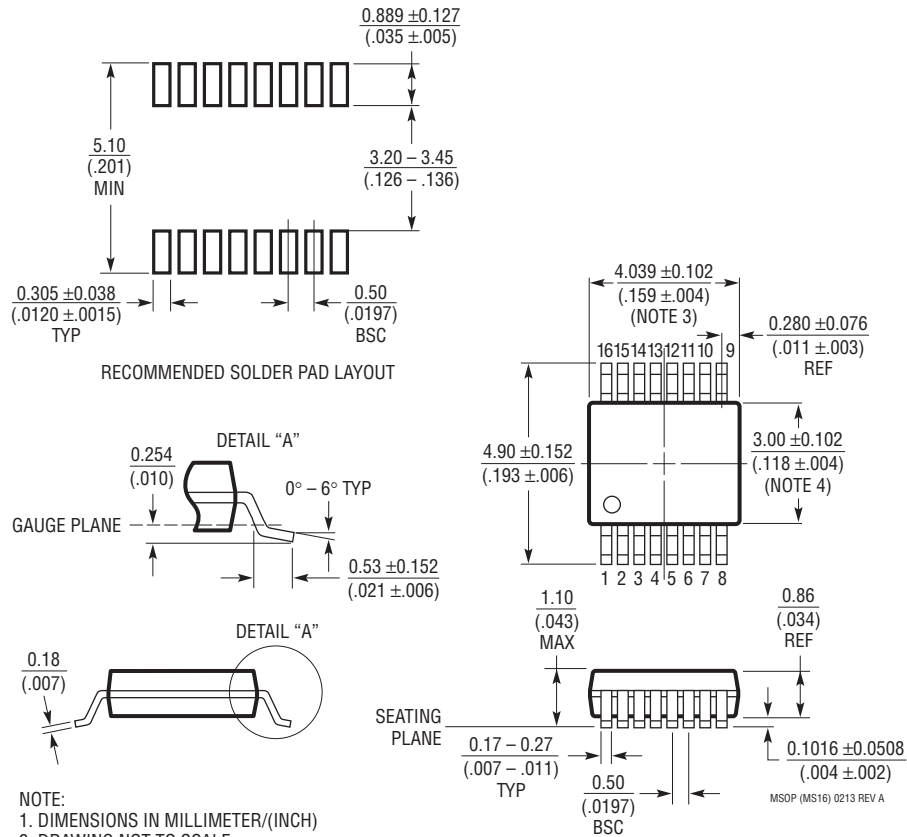


PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LTC2326-16#packaging> for the most recent package drawings.

MS Package 16-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1669 Rev A)



NOTE:

1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX

REVISION HISTORY

REV	DATE	DESCRIPTION	PAGE NUMBER
A	07/16	Updated graphs G01, G02 and G03	7